

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L5	1303	source near3 drain with (ge germanium)	US-PGPUB; USPAT; USOCR	OR	OFF	2005/08/12 16:14
L6	859	5 same (Si silicon SiGe)	US-PGPUB; USPAT; USOCR	OR	OFF	2005/08/12 16:14
L7	397	6 and gate with spacer\$1	US-PGPUB; USPAT; USOCR	OR	OFF	2005/08/12 16:14
L8	54	7 and substrate with single adj crystal	US-PGPUB; USPAT; USOCR	OR	OFF	2005/08/12 16:15
L11	655	(257/192).CCLS.	USPAT	OR	OFF	2005/08/12 16:24
L12	277	(257/616).CCLS.	USPAT	OR	OFF	2005/08/12 16:25
L13	143	(257/19).CCLS.	USPAT	OR	OFF	2005/08/12 16:25
L14	577	(257/336).CCLS.	USPAT	OR	OFF	2005/08/12 16:26
L15	798	(257/344).CCLS.	USPAT	OR	OFF	2005/08/12 16:26